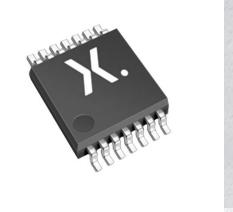


74AHCT00PW-Q100J Datasheet

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DiGi Electronics Part Number 74AHCT00PW-Q100J-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number 74AHCT00PW-Q100J

Description IC GATE NAND 4CH 2-INP 14TSSOP

Detailed Description NAND Gate IC 4 Channel 14-TSSOP



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|------------------------------|------------------------------------|
| 74AHCT00PW-Q100J | Nexperia USA Inc. |
| Series: | Product Status: |
| 74AHCT | Active |
| Logic Type: | Number of Circuits: |
| NAND Gate | 4 |
| Number of Inputs: | Features: |
| 2 | |
| Voltage - Supply: | Current - Quiescent (Max): |
| 4.5V ~ 5.5V | 2 μΑ |
| Current - Output High, Low: | Input Logic Level - Low: |
| 8mA, 8mA | 0.8V |
| Input Logic Level - High: | Max Propagation Delay @ V, Max CL: |
| 2V | 7.9ns @ 5V, 50pF |
| Operating Temperature: | Grade: |
| -40°C ~ 125°C | Automotive |
| Qualification: | Mounting Type: |
| AEC-Q100 | Surface Mount |
| Supplier Device Package: | Package / Case: |
| 14-TSSOP | 14-TSSOP (0.173", 4.40mm Width) |
| Base Product Number: | |
| 74AHCT00 | |

Environmental & Export classification

8542.39.0001

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |

Quad 2-input NAND gate Rev. 4 — 15 January 2024

Product data sheet

1. General description

The 74AHC00-Q100; 74AHCT00-Q100 are quad 2-input NAND gates. Inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 5.5 V
- · Input levels:
 - For 74AHC00-Q100: CMOS level
 - For 74AHCT00-Q100: TTL level
- · Balanced propagation delays
- · All inputs have Schmitt-trigger actions
- Overvoltage tolerant inputs to 5.5 V
- · High noise immunity
- CMOS low power dissipation
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- · Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

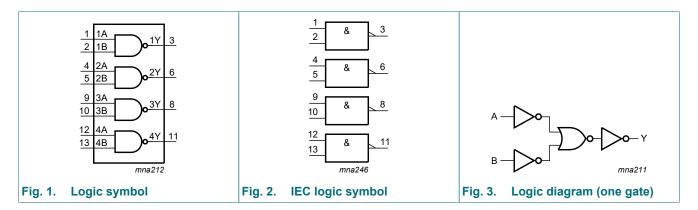
3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | | | |
|-----------------------------------|-------------------|----------|------------------------------------------------------------------------------------------------------------------------------|----------|--|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | | |
| 74AHC00D-Q100 74AHCT00D-Q100 | -40 °C to +125 °C | SO14 | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 | | | | | | |
| 74AHC00PW-Q100 74AHCT00PW-Q100 | -40 °C to +125 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads; body width 4.4 mm | SOT402-1 | | | | | | |
| 74AHC00BQ-Q100 74AHCT00BQ-Q100 | -40 °C to +125 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm | SOT762-1 | | | | | | |

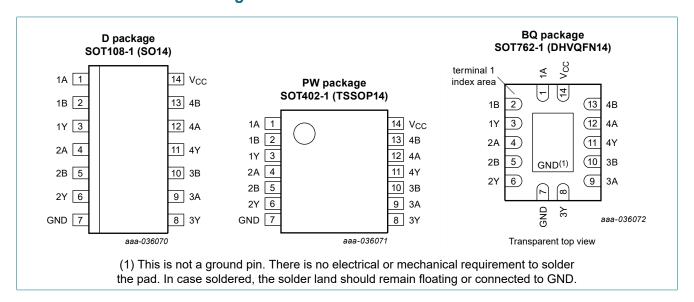


4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|--------------|----------------|
| 1A, 2A, 3A, 4A | 1, 4, 9, 12 | data inputs |
| 1B, 2B, 3B, 4B | 2, 5, 10, 13 | data inputs |
| 1Y, 2Y, 3Y, 4Y | 3, 6, 8, 11 | data outputs |
| GND | 7 | ground (0 V) |
| V _{CC} | 14 | supply voltage |

6. Functional description

Table 3. Function selection

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

| Input | | Output |
|-------|----|--------|
| nA | nB | nY |
| L | X | Н |
| X | L | Н |
| Н | Н | L |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|-------------------------------------------------------------|-----|------|------|------|
| V _{CC} | supply voltage | | | -0.5 | +7.0 | V |
| VI | input voltage | | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < -0.5 V | [1] | -20 | - | mA |
| I _{OK} | output clamping current | $V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$ | [1] | -20 | +20 | mA |
| Io | output current | $V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$ | | -25 | +25 | mA |
| I _{CC} | supply current | | | - | +75 | mA |
| I _{GND} | ground current | | | -75 | - | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | [2] | - | 500 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

For SOT762-1 (DHVQFN14) package: Ptot derates linearly with 9.6 mW/K above 98 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 74 | 74AHC00-Q100 | | 74AHCT00-Q100 | | | Unit |
|------------------|---------------------------|--------------------------------------------|-----|--------------|-----------------|---------------|-----|-----------------|------|
| | | | Min | Тур | Max | Min | Тур | Max | |
| V _{CC} | supply voltage | | 2.0 | 5.0 | 5.5 | 4.5 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | 5.5 | 0 | - | 5.5 | V |
| Vo | output voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | - | - | 100 | - | - | - | ns/V |
| | fall rate | $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | - | - | 20 | - | - | 20 | ns/V |

^[2] For SOT108-1 (SO14) package: Ptot derates linearly with 10.1 mW/K above 100 °C.

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | 25 °C | | -40 °C t | o +85 °C | -40 °C to | +125 °C | Unit |
|-----------------|--------------------------|-------------------------------------------------------------------------------------------|------|-------|------|----------|----------|-----------|---------|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| 74AHC0 | 0-Q100 | | | | | | | | | 1 |
| V _{IH} | HIGH-level | V _{CC} = 2.0 V | 1.5 | - | - | 1.5 | - | 1.5 | - | ٧ |
| | input voltage | V _{CC} = 3.0 V | 2.1 | - | - | 2.1 | - | 2.1 | - | ٧ |
| | | V _{CC} = 5.5 V | 3.85 | - | - | 3.85 | - | 3.85 | - | V |
| V _{IL} | LOW-level | V _{CC} = 2.0 V | - | - | 0.5 | - | 0.5 | - | 0.5 | ٧ |
| | input voltage | V _{CC} = 3.0 V | - | - | 0.9 | - | 0.9 | - | 0.9 | V |
| | | V _{CC} = 5.5 V | - | - | 1.65 | - | 1.65 | - | 1.65 | ٧ |
| V _{OH} | HIGH-level | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | output voltage | I_{O} = -50 μ A; V_{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | ٧ |
| | | I _O = -50 μA; V _{CC} = 3.0 V | 2.9 | 3.0 | - | 2.9 | - | 2.9 | - | ٧ |
| | | I _O = -50 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | ٧ |
| | | I_{O} = -4.0 mA; V_{CC} = 3.0 V | 2.58 | - | - | 2.48 | - | 2.40 | - | ٧ |
| | | I _O = -8.0 mA; V _{CC} = 4.5 V | 3.94 | - | - | 3.80 | - | 3.70 | - | V |
| V _{OL} | LOW-level | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | output voltage | I _O = 50 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | ٧ |
| | | I _O = 50 μA; V _{CC} = 3.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | ٧ |
| | | I _O = 50 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | ٧ |
| | | $I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.36 | - | 0.44 | - | 0.55 | ٧ |
| | | I _O = 8.0 mA; V _{CC} = 4.5 V | - | - | 0.36 | - | 0.44 | - | 0.55 | ٧ |
| l _l | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μA |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$ | - | - | 2.0 | - | 20 | - | 40 | μΑ |
| Cı | input capacitance | V _I = V _{CC} or GND | - | 3.0 | 10 | - | 10 | - | 10 | pF |
| 74AHCT | 00-Q100 | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH-level | $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$ | | | | | | | | |
| | output voltage | I _O = -50 μA | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = -8.0 mA | 3.94 | - | - | 3.80 | - | 3.70 | - | ٧ |
| V _{OL} | LOW-level | $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$ | | | | | | | | |
| | output voltage | Ι _Ο = 50 μΑ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 8.0 mA | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| l _l | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μA |
| I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V | - | - | 2.0 | - | 20 | - | 40 | μA |

Quad 2-input NAND gate

| Symbol | Parameter | Conditions | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | |
|------------------|---------------------------|---------------------------------------------------------------------------------------------------------------------------------------------|-------|-----|------------------|-----|-------------------|-----|------|----|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| ΔI _{CC} | additional supply current | per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other pins at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V | - | - | 1.35 | - | 1.5 | - | 1.5 | mA |
| Cı | input capacitance | V _I = V _{CC} or GND | - | 3.0 | 10 | - | 10 | - | 10 | pF |

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

| Symbol | Parameter | Conditions | | | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|-----------------|-------------------------------------|----------------------------------------------------------|-----|-----|--------|------|------------------|------|-------------------|------|------|
| | | | | Min | Typ[1] | Max | Min | Max | Min | Max | |
| 74AHC0 | 0-Q100 | | | | | | | | | | |
| t _{pd} | propagation | nA, nB to nY; see Fig. 4 | [2] | | | | | | | | |
| | delay | V _{CC} = 3.0 V to 3.6 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 4.5 | 7.9 | 1.0 | 9.5 | 1.0 | 10.0 | ns |
| | | C _L = 50 pF | | - | 6.0 | 11.4 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 3.2 | 5.5 | 1.0 | 6.5 | 1.0 | 7.0 | ns |
| | | C _L = 50 pF | | - | 4.5 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| C _{PD} | power dissipation capacitance | C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC} | [3] | - | 7.0 | - | - | - | - | - | pF |
| 74AHCT | 00-Q100 | | | | | | | | 1 | | |
| t _{pd} | propagation | nA, nB to nY; see Fig. 4 | [2] | | | | | | | | |
| | delay | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 3.3 | 6.9 | 1.0 | 8.0 | 1.0 | 9.0 | ns |
| | | C _L = 50 pF | | - | 4.5 | 7.9 | 1.0 | 9.0 | 1.0 | 10.0 | ns |
| C _{PD} | power dissipation capacitance | C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC} | [3] | - | 7.0 | - | - | - | - | - | pF |

^[1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

10.1. Waveforms

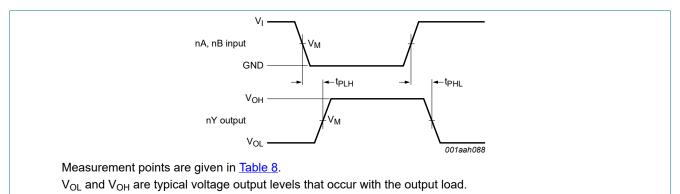
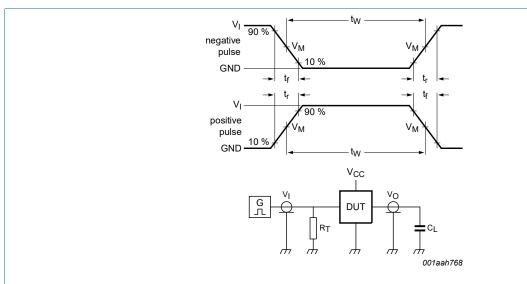


Fig. 4. Input to output propagation delays

Table 8. Measurement points

| Туре | Input | Output |
|---------------|-----------------------|-----------------------|
| | V _M | V _M |
| 74AHC00-Q100 | 0.5 × V _{CC} | 0.5 × V _{CC} |
| 74AHCT00-Q100 | 1.5 V | 0.5 × V _{CC} |



Test data is given in Table 9.

Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = load capacitance including jig and probe capacitance.

Fig. 5. Test circuit for measuring switching times

Table 9. Test data

| Туре | Input | | Load | Test |
|---------------|-----------------|---------------------------------|--------------|-------------------------------------|
| | VI | t _r , t _f | CL | |
| 74AHC00-Q100 | V _{CC} | ≤ 3.0 ns | 15 pF, 50 pF | t _{PLH} , t _{PHL} |
| 74AHCT00-Q100 | 3.0 V | ≤ 3.0 ns | 15 pF, 50 pF | t _{PLH} , t _{PHL} |

11. Package outline

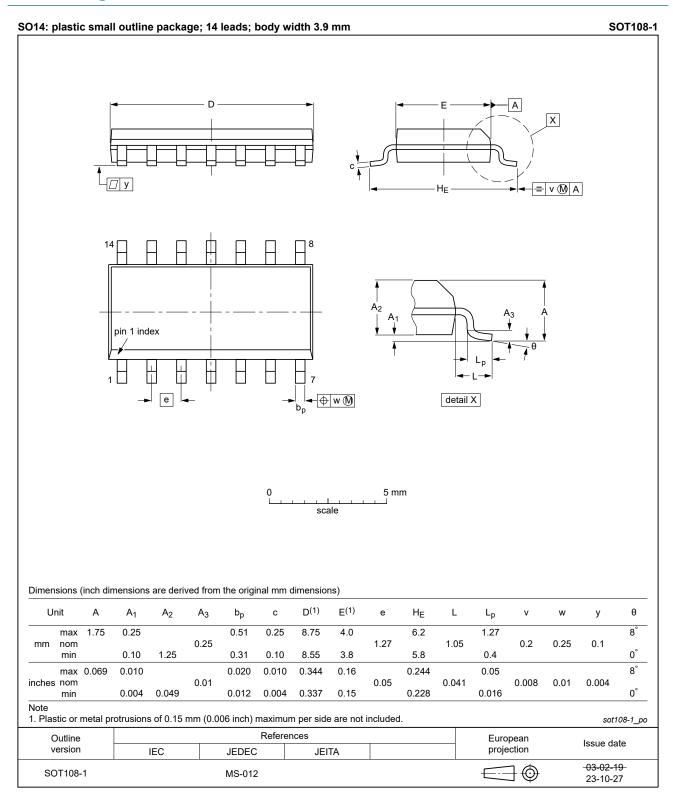


Fig. 6. Package outline SOT108-1 (SO14)

Quad 2-input NAND gate

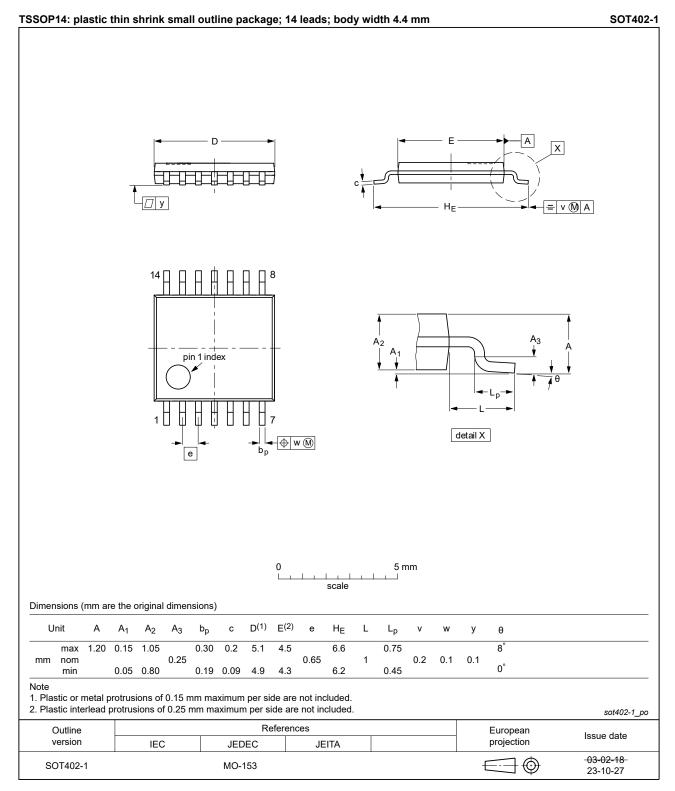


Fig. 7. Package outline SOT402-1 (TSSOP14)

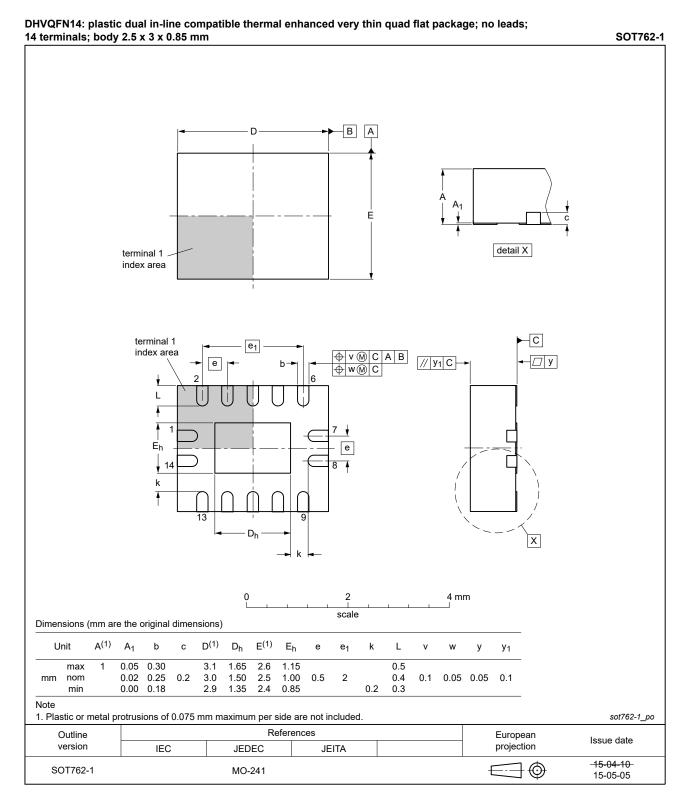


Fig. 8. Package outline SOT762-1 (DHVQFN14)

12. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|-----------------------------------------|
| CDM | Charge Device Model |
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| TTL | Transistor-Transistor Logic |

13. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|-----------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|---------------|-----------------------|--|--|
| 74AHC_AHCT00_Q100 v.4 | 20240115 | Product data sheet | - | 74AHC_AHCT00_Q100 v.3 | | |
| Modifications: | Section 2: ESD specification updated according to the latest JEDEC standard. Fig. 6, Fig. 7: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153. | | | | | |
| 74AHC_AHCT00_Q100 v.3 | 20230901 | Product data sheet | - | 74AHC_AHCT00_Q100 v.2 | | |
| Modifications: | <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard. | | | | | |
| 74AHC_AHCT00_Q100 v.2 | 20200526 | Product data sheet | - | 74AHC_AHCT00_Q100 v.1 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 1 and Section 2 updated. Table 4: Derating values for P_{tot} total power dissipation have been updated. Package outline drawing of SOT762-1 (Fig. 8) updated. | | | | | |
| 74AHC_AHCT00_Q100 v.1 | 20130416 | Product specification | - | - | | |

Quad 2-input NAND gate

14. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
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Quad 2-input NAND gate

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